



2SA1784/2SC4644

High Voltage Driver Applications

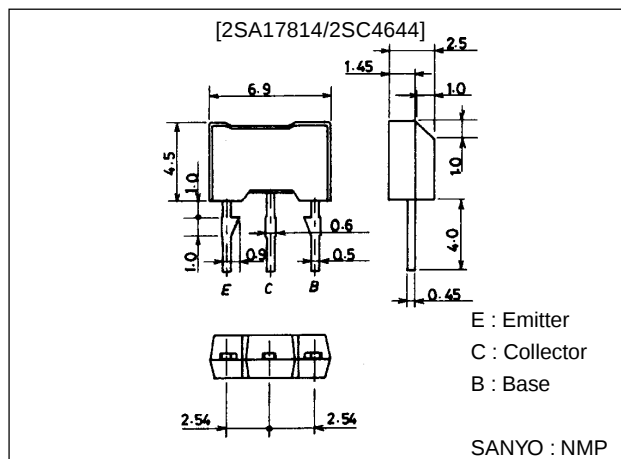
Features

- Adoption of MBIT process.
- High breakdown voltage ($V_{CEO} \geq 400V$).
- Excellent linearity of h_{FE} .

Package Dimensions

unit:mm

2064



() : 2SA1784

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-)400	V
Collector-to-Emitter Voltage	V_{CEO}		(-)400	V
Emitter-to-Base Voltage	V_{EBO}		(-)5	V
Collector Current	I_C		(-)200	mA
Collector Current (Pulse)	I_{CP}		(-)400	mA
Collector Dissipation	P_C		1	W
Junction Temperature	T_J		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Electrical Characteristics at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)300V, I_E=0$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0$			(-)0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)10V, I_C=(-)50mA$	60*		200*	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)30V, I_C=(-)10mA$		70		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)30V, f=1MHz$		(5)4		pF
Reverse Transfer Capacitance	C_{re}	$V_{CB}=(-)30V, f=1MHz$		(4)3		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)50mA, I_B=(-)5mA$			(-0.8)	V
					0.6	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)50mA, I_B=(-)5mA$			(-)1.0	V

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83198HA (KT)/5170TA (KOTO) No.3520-1/4

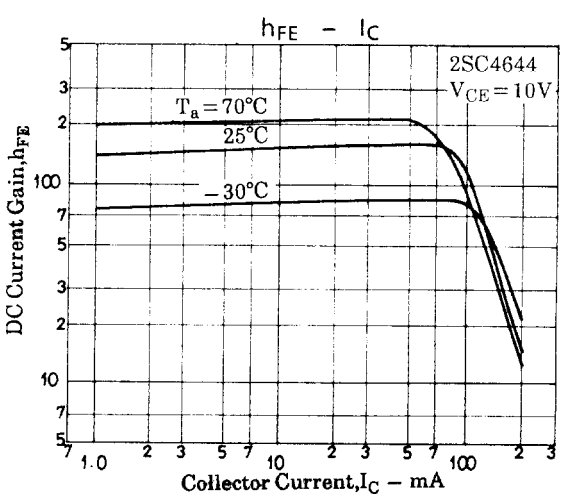
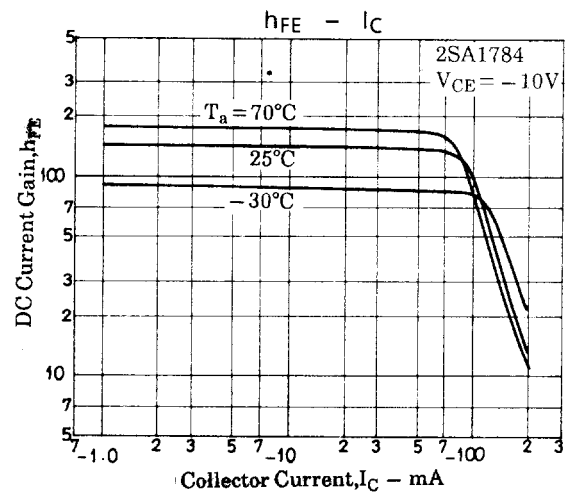
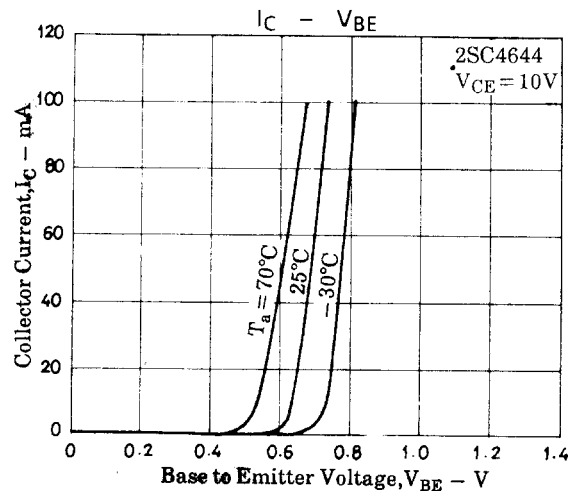
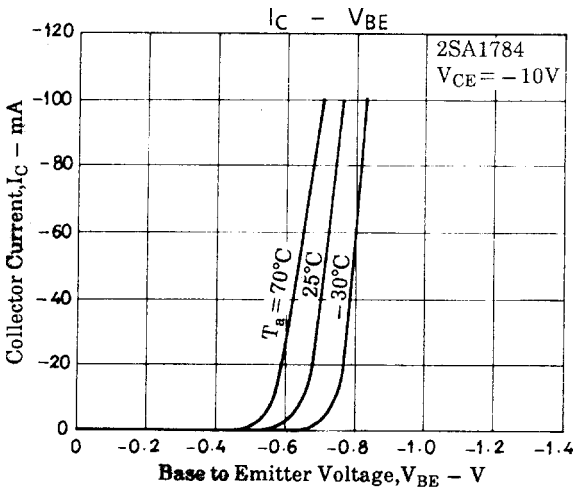
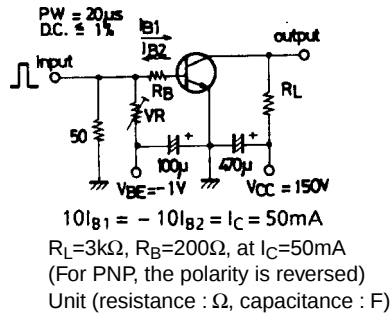
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)400			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)400			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)5			V
Turn-ON Time	t_{on}	See specified Test Circuit		0.25		μs
Turn-OFF Time	t_{off}	See specified Test Circuit		5.0		μs

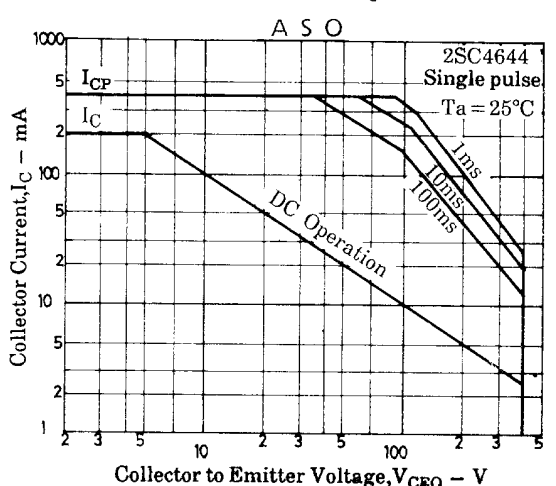
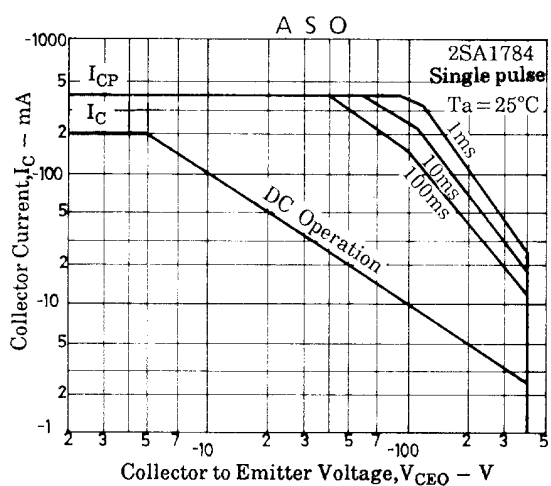
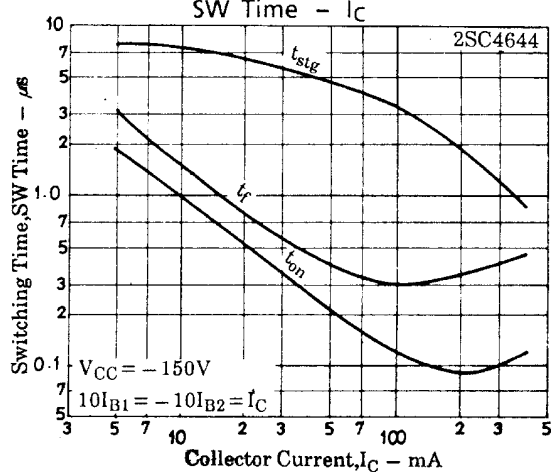
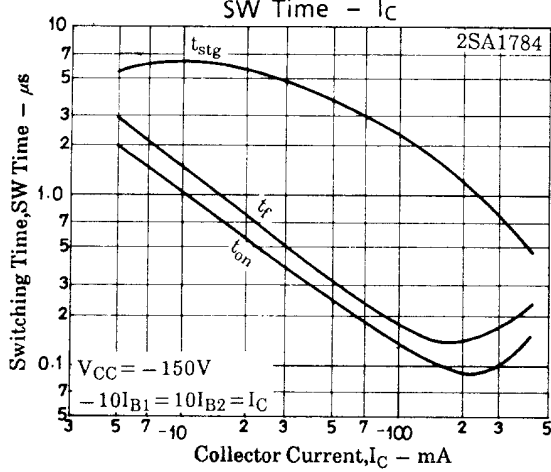
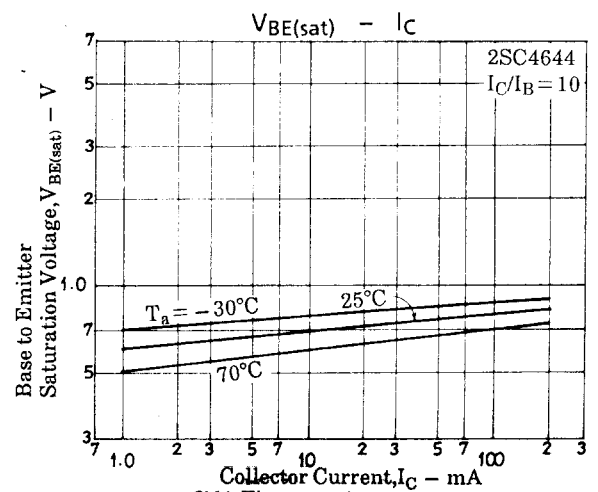
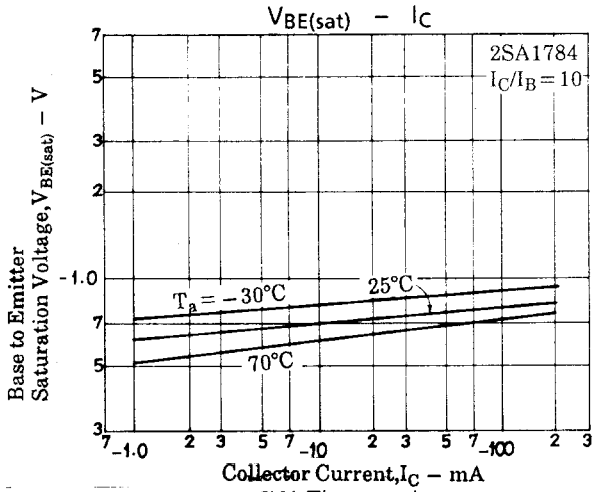
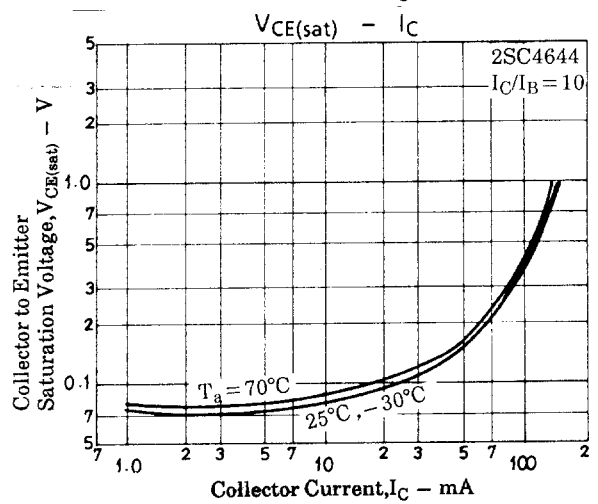
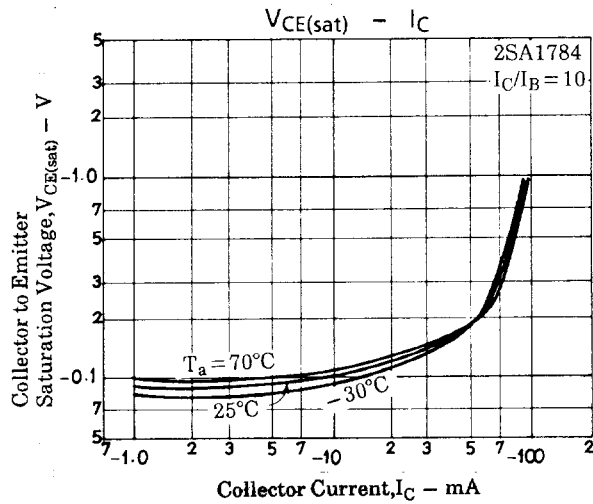
* : The 2SA1784/2SC4644 are classified by 50mA h_{FE} as follows :

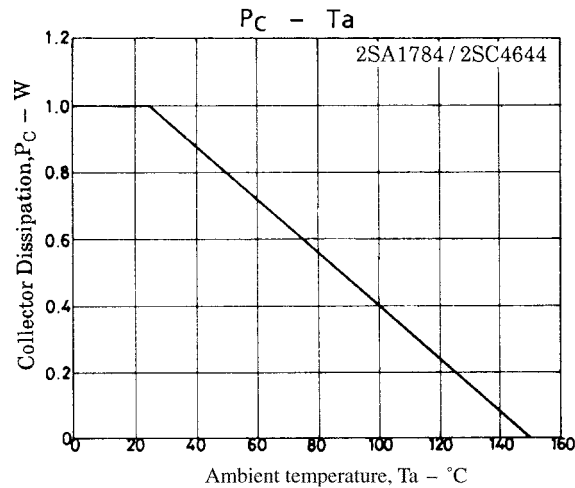
60	D	120	100	E	200
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Switching Time Test Circuit



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